

Low voltage NPN power transistors

Features

- Low saturation voltage
- NPN transistors

Applications

- Audio, power linear and switching applications

Description

The devices are manufactured in Planar technology with “Base Island” layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage. The PNP type is BD238.

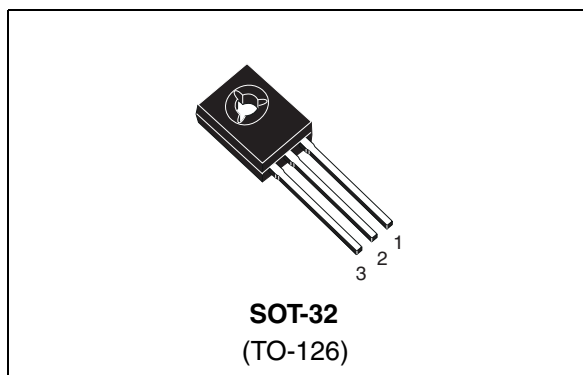


Figure 1. Internal schematic diagram

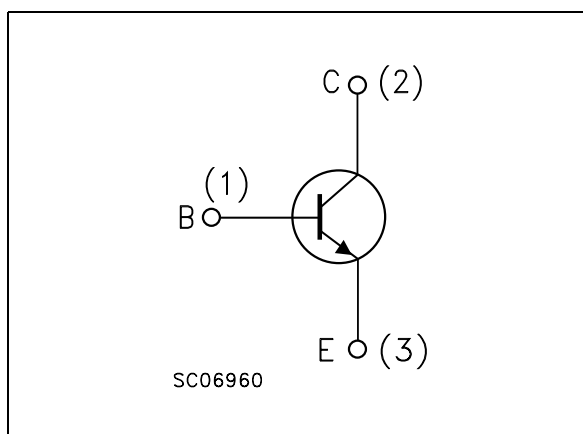


Table 1. Device summary

Order codes	Marking	Package	Packaging
BD235	BD235	SOT-32	Tube
BD237	BD237	SOT-32	Tube

1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value		Unit
		BD235	BD237	
V_{CBO}	Collector-base voltage ($I_E = 0$)	60	100	V
V_{CER}	Collector-emitter voltage ($R_{BE} = 1\text{ k}\Omega$)	60	100	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	60	80	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	5		V
I_C	Collector current	2		A
I_{CM}	Collector peak current ($t_p < \text{ms}$)	6		A
P_{TOT}	Total dissipation at $T_{case} = 25^\circ\text{C}$	25		W
T_{stg}	Storage temperature	-65 to 150		$^\circ\text{C}$
T_J	Max. operating junction temperature	150		$^\circ\text{C}$

2 Electrical characteristics

($T_{\text{case}} = 25^{\circ}\text{C}$; unless otherwise specified)

Table 3. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector cut-off current ($I_{\text{E}} = 0$)	$V_{\text{CB}} = \text{rated } V_{\text{CBO}}$ $V_{\text{CB}} = \text{rated } V_{\text{CBO}} \quad T_{\text{C}} = 150^{\circ}\text{C}$		-	0.1 2	mA mA
I_{EBO}	Emitter cut-off current ($I_{\text{C}} = 0$)	$V_{\text{EB}} = 5\text{V}$		-	1	mA
$V_{\text{CEO(sus)}}^{(1)}$	Collector-emitter sustaining voltage ($I_{\text{B}} = 0$)	$I_{\text{C}} = 100\text{mA}$ for BD235 for BD237	60 80	-		V V
$V_{\text{CE(sat)}}^{(1)}$	Collector-emitter saturation voltage	$I_{\text{C}} = 1\text{A} \quad I_{\text{B}} = 0.1\text{A}$		-	0.6	V
$V_{\text{BE(on)}}^{(1)}$	Base-emitter on voltage	$I_{\text{C}} = 1\text{A} \quad V_{\text{CE}} = 2\text{V}$		-	1.3	V
$h_{\text{FE}}^{(1)}$	DC current gain	$I_{\text{C}} = 150\text{mA} \quad V_{\text{CE}} = 2\text{V}$ $I_{\text{C}} = 1\text{A} \quad V_{\text{CE}} = 2\text{V}$	40 25	-		

1. Pulsed duration = 300 μs , duty cycle = 1.5 %.

2.1 Electrical characteristic (curves)

Figure 2. Safe operating area

Figure 3. Derating curves

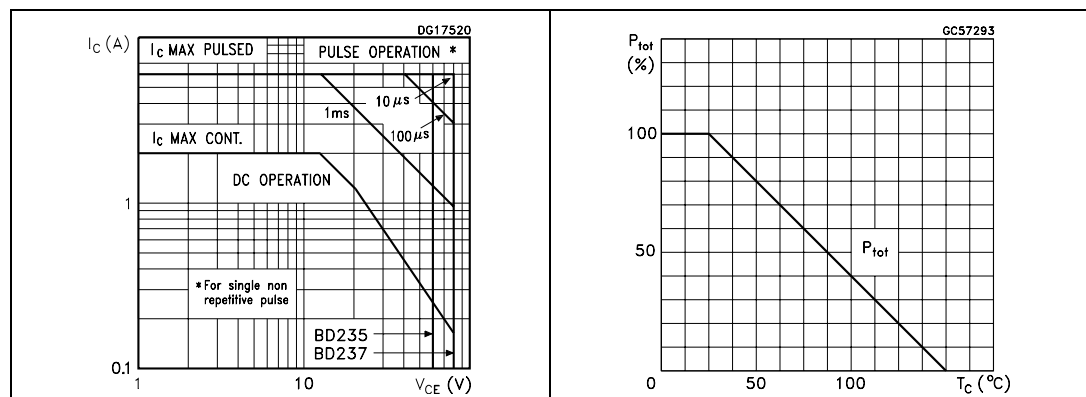


Figure 4. DC current gain ($V_{CE} = 2\text{ V}$)

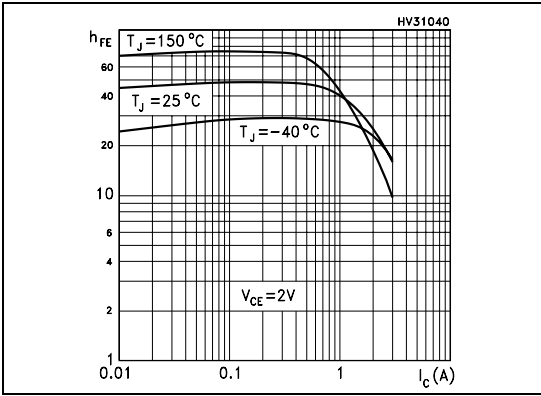


Figure 5. DC current gain ($V_{CE} = 4\text{ V}$)

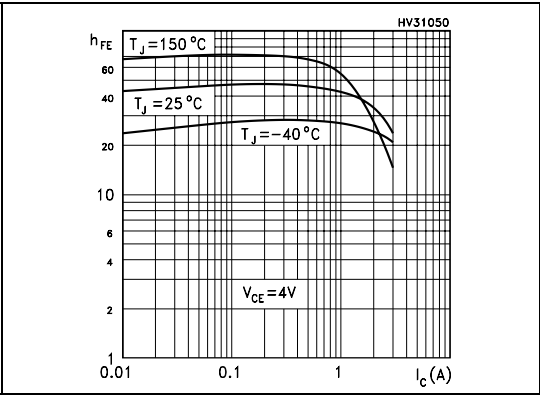


Figure 6. Collector-emitter saturation voltage

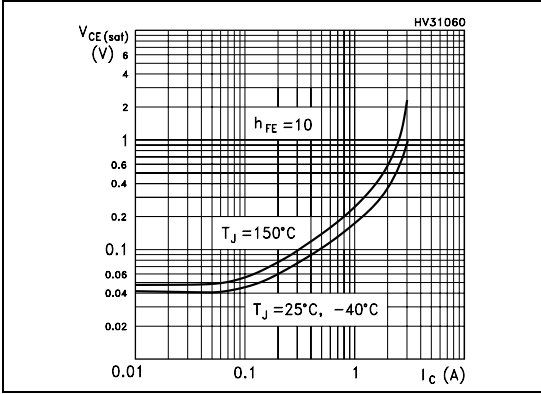


Figure 7. Base-emitter saturation voltage

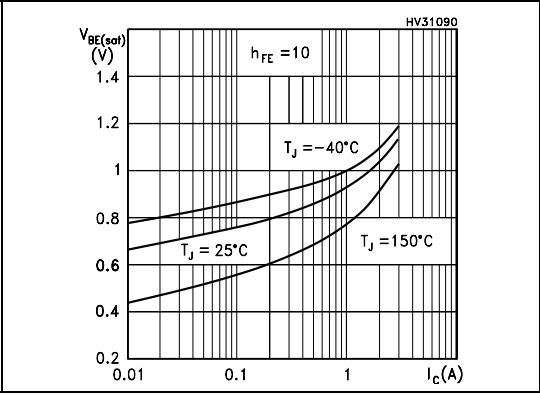


Figure 8. Base-emitter on voltage

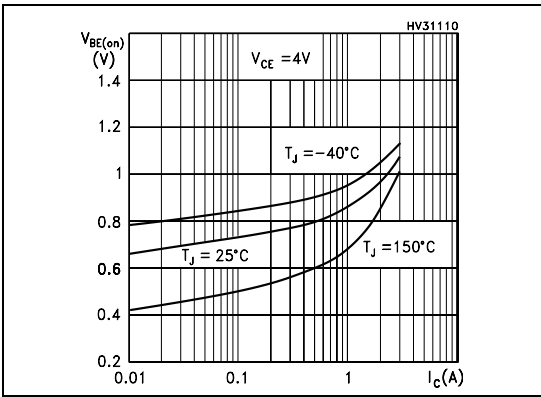


Figure 9. Resistive load switching time (on)

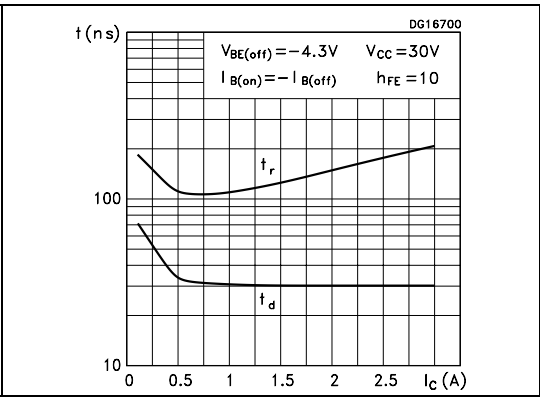
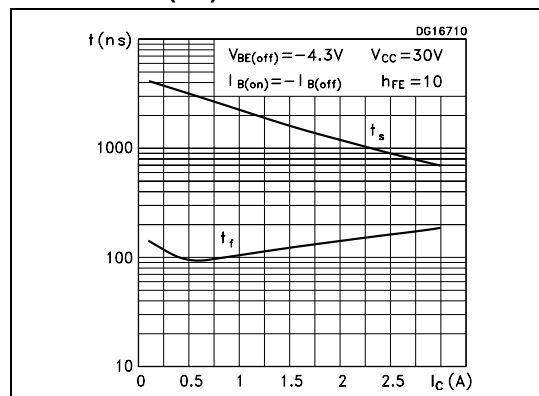
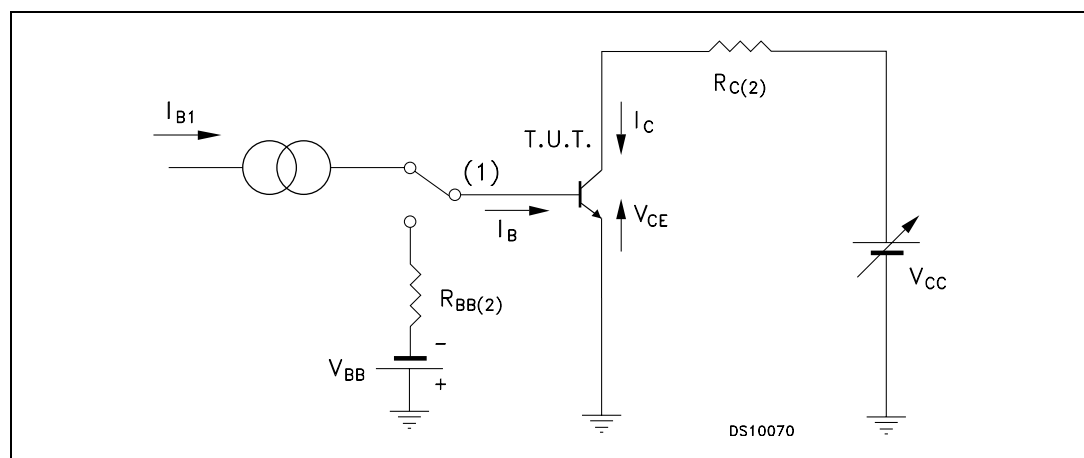


Figure 10. Resistive load switching time (off)



2.2 Test circuit

Figure 11. Resistive load switching test circuit



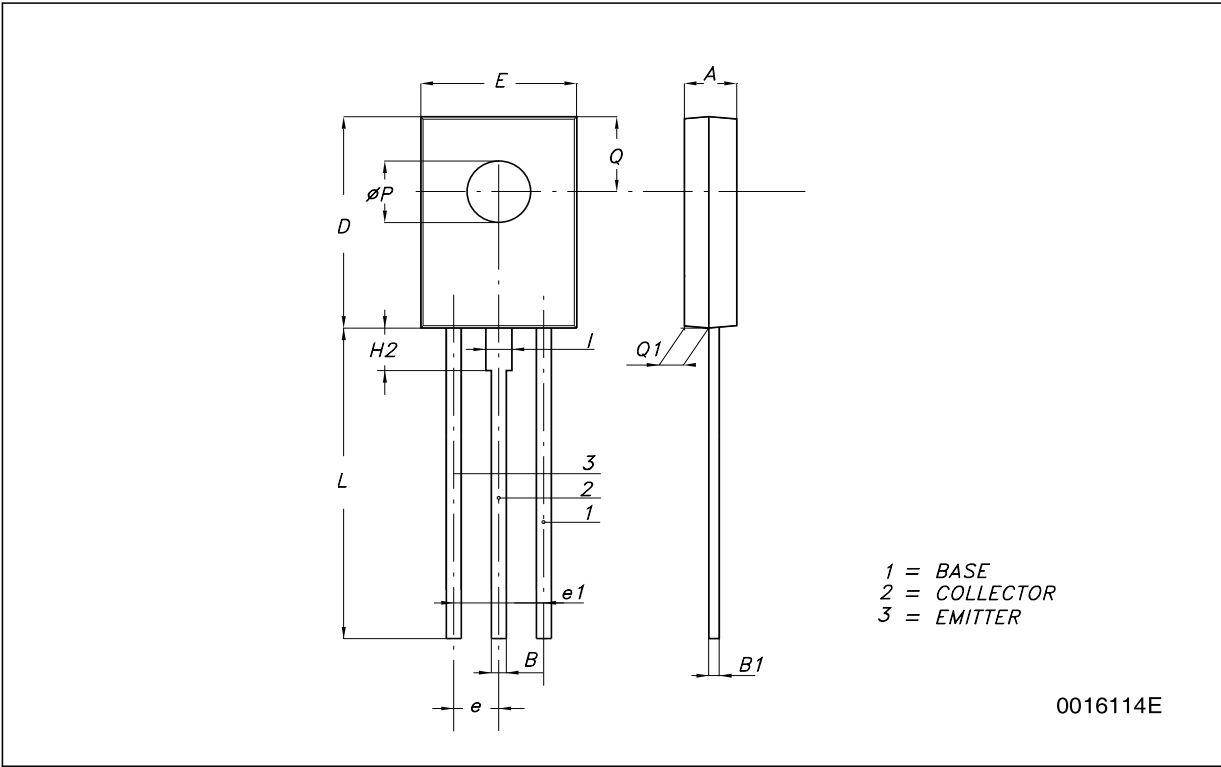
1. Fast electronic switch
2. Non-inductive resistor

3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

SOT-32 (TO-126) MECHANICAL DATA

DIM.	mm.		
	MIN.	TYP	MAX.
A	2.4		2.9
B	0.64		0.88
B1	0.39		0.63
D	10.5		11.05
E	7.4		7.8
e	2.04	2.29	2.54
e1	4.07	4.58	5.08
L	15.3		16
P	2.9		3.2
Q		3.8	
Q1	1		1.52
H2		2.15	
I		1.27	



4 Revision history

Table 4. Document revision history

Date	Revision	Changes
11-Feb-2003	1	Initial release.
09-Jul-2007	2	Added: figures 2, 3, 4, 5, 6, 7, 8, 9, 10, 11 and 12.
03-Jun-2009	3	Minor text changes.

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2009 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com